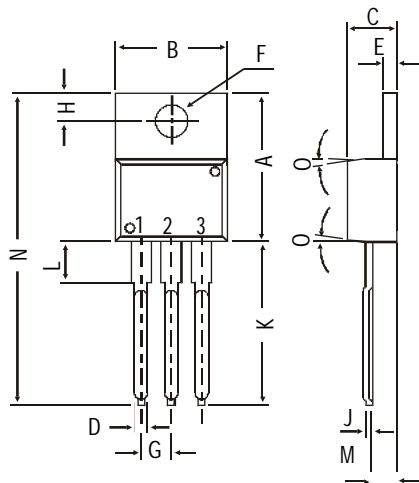
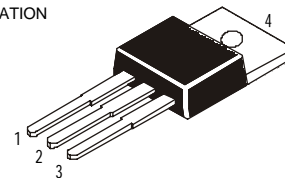


TO-220 Plastic Package

CSC2335

CSC2335 NPN PLASTIC POWER TRANSISTOR
High Speed, High Voltage Switching

PIN CONFIGURATION
 1. BASE
 2. COLLECTOR
 3. EMITTER
 4. COLLECTOR



DIM	MIN.	MAX.
A	14.42	16.51
B	9.63	10.67
C	3.56	4.83
D		0.90
E	1.15	1.40
F	3.75	3.88
G	2.29	2.79
H	2.54	3.43
J		0.56
K	12.70	14.73
L	2.80	4.07
M	2.03	2.92
N		31.24
O	DEG 7	

All dimensions in mm.

ABSOLUTE MAXIMUM RATINGS

Collector-base voltage (open emitter)
 Collector-emitter voltage (open base)
 Collector current (D.C.)
 Total power dissipation up to $T_C = 25^\circ\text{C}$
 Junction temperature
 Collector-emitter saturation voltage
 $I_C = 3\text{A}; I_B = 0.6\text{A}$
 D.C. current gain
 $I_C = 0.1\text{A}; V_{CE} = 5\text{V}$

V_{CBO}	max.	500 V
V_{CEO}	max.	400 V
I_C	max.	7.0 A
P_{tot}	max.	40 W
T_j	max.	150 °C
V_{CEsat}	max.	1.0 V
h_{FE}	min.	20
	max.	80

RATINGS (at $T_A=25^\circ\text{C}$ unless otherwise specified)

Limiting values
 Collector-base voltage (open emitter)
 Collector-emitter voltage (open base)
 Emitter-base voltage (open collector)
 Collector current (DC)

V_{CBO}	max.	500 V
V_{CEO}	max.	400 V
V_{EBO}	max.	7.0 V
I_C	max.	7.0 A

Collector current (Pulse value) (1)	I_C	max.	15 A
Base current (DC)	I_B	max.	3.5 A
Total power dissipation up to $T_C = 25^\circ\text{C}$	P_{tot}	max.	40 W
Total power dissipation up to $T_A = 25^\circ\text{C}$	P_{tot}	max.	1.5 W
Junction temperature	T_j	max.	150 °C
Storage temperature	T_{stg}		-65 to +150 °C

THERMAL CHARACTERISTICS

From junction to case	R_{thj-c}		3.125 °C/W
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CHARACTERISTICS

$T_{amb} = 25^\circ\text{C}$ unless otherwise specified

Collector cutoff current

$$I_E = 0; V_{CB} = 400V$$

$$R_{BE} = 51\Omega; V_{CE} = 400V; T_A = 125^\circ\text{C}$$

$$V_{BE(off)} = 1.5V; V_{CE} = 400V$$

$$V_{BE(off)} = 1.5V; V_{CE} = 400V; T_A = 125^\circ\text{C}$$

Emitter cut-off current

$$I_C = 0; V_{EB} = 5V$$

Breakdown voltages

$$I_C = 3 \text{ A}; I_{B1} = 0.6 \text{ A}; L = 1 \text{ mH}$$

$$I_C = 1 \text{ mA}; I_E = 0$$

$$I_E = 1 \text{ mA}; I_C = 0$$

Saturation voltages

$$I_C = 3 \text{ A}; I_B = 0.6 \text{ A}$$

D.C. current gain

$$I_C = 0.1 \text{ A}; V_{CE} = 5V$$

$$I_C = 1 \text{ A}; V_{CE} = 5V^{**}$$

$$I_C = 3 \text{ A}; V_{CE} = 5V$$

Switching time

$$I_C = 3 \text{ A}; R_L = 50\Omega$$

$$I_{B1} = -I_{B2} = 0.6 \text{ A}; V_{CC} = 150V$$

Turn on time**Storage time****Fall time**

$$I_{CBO} \quad \text{max.} \quad 10 \mu\text{A}$$

$$I_{CER} \quad \text{max.} \quad 1.0 \text{ mA}$$

$$I_{CEX} \quad \text{max.} \quad 10 \mu\text{A}$$

$$I_{CEX} \quad \text{max.} \quad 1.0 \text{ mA}$$

$$I_{EBO} \quad \text{max.} \quad 10 \mu\text{A}$$

$$V_{CEO(sus)}^* \quad \text{min.} \quad 400 \text{ V}$$

$$V_{CBO} \quad \text{min.} \quad 500 \text{ V}$$

$$V_{EBO} \quad \text{min.} \quad 7.0 \text{ V}$$

$$V_{CEsat}^* \quad \text{max.} \quad 1.0 \text{ V}$$

$$V_{BEsat}^* \quad \text{max.} \quad 1.2 \text{ V}$$

$$h_{FE}^* \quad \text{min.} \quad 20$$

$$\text{max.} \quad 80$$

$$h_{FE}^* \quad \text{min.} \quad 20$$

$$\text{max.} \quad 80$$

$$h_{FE}^* \quad \text{min.} \quad 10$$

$$t_{on} \quad \text{max.} \quad 1.0 \mu\text{s}$$

$$t_s \quad \text{max.} \quad 2.5 \mu\text{s}$$

$$t_f \quad \text{max.} \quad 1.0 \mu\text{s}$$

* Pulse test: $P_W \leq 350 \mu\text{s}$; duty cycle $\leq 2\%$ pulsed.

(1) $P_W \leq 300 \mu\text{s}$; duty cycle $\leq 10\%$.

** h_{FE} classification: **R: 20-40 O: 30-60 Y: 40-80**

Customer Notes

Disclaimer

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